

# EVVOSEMI<sup>®</sup>

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

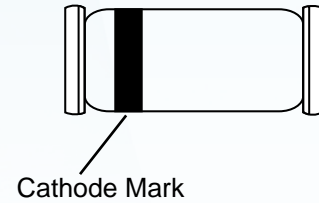
## Product Specification

▶ Domestic	Part Number	LL4148
▶ Overseas	Part Number	LL4148
▶ Equivalent	Part Number	LL4148

EV is the abbreviation of name EVVO

## ■ Silicon Epitaxial Planar Switching Diode

- Fast switching diode in MiniMELF case especially suited for automatic surface mounting



### ■ Simplified outline(LL-34/SOD-80)

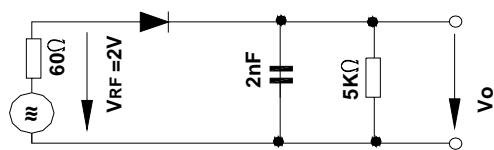
### ■ Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

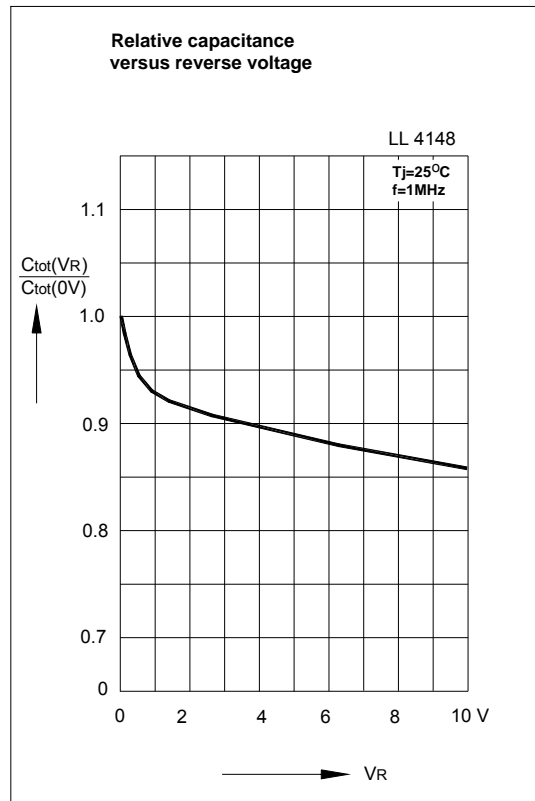
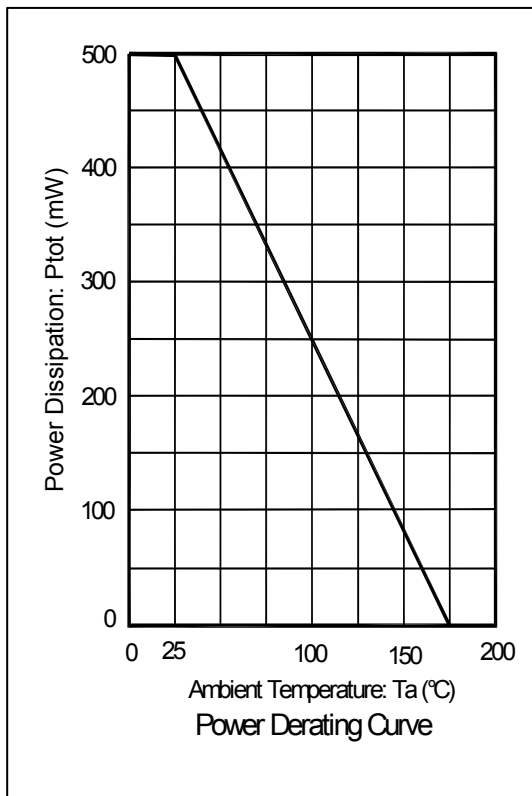
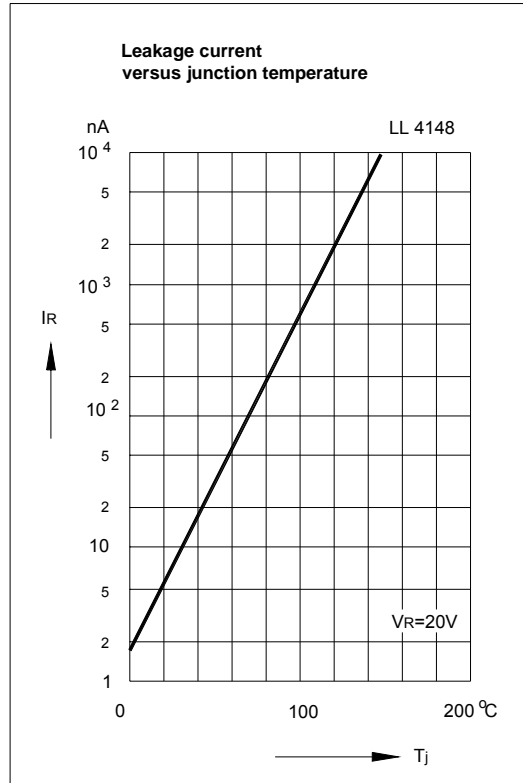
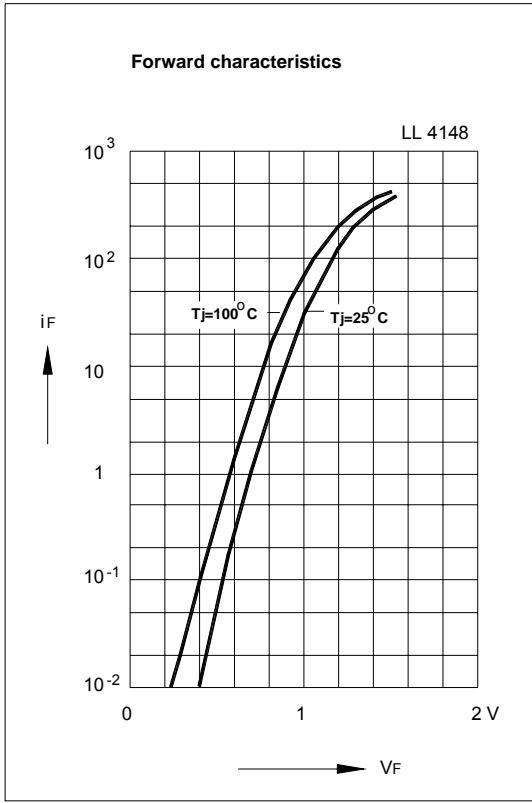
Parameter	Symbol	Value	Unit
Peak Reverse Voltage	$V_{RM}$	100	V
Reverse Voltage	$V_R$	75	V
Average Rectified Forward Current	$I_{F(AV)}$	200	mA
Non-repetitive Peak Forward Surge Current	$I_{FSM}$	0.5	A
at t = 1 s		1	
at t = 1 ms		4	
Power Dissipation	$P_{tot}$	500 <sup>1)</sup>	mW
Junction Temperature	$T_j$	175	$^{\circ}\text{C}$
Storage Temperature Range	$T_{stg}$	- 65 to + 175	$^{\circ}\text{C}$

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.

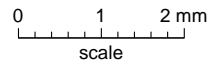
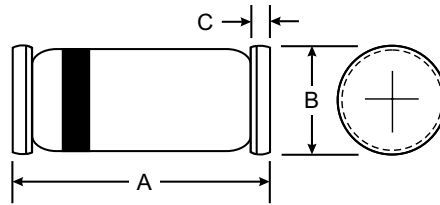
**■ Characteristics at  $T_a = 25^\circ\text{C}$** 

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage tested with 100 $\mu\text{A}$ Pulses	$V_{(BR)R}$	100	-	V
Forward Voltage at $I_F = 10 \text{ mA}$	$V_F$	-	1	V
Leakage Current at $V_R = 20 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 20 \text{ V}, T_j = 150^\circ\text{C}$	$I_R$ $I_R$ $I_R$	- - -	25 5 50	nA $\mu\text{A}$ $\mu\text{A}$
Capacitance at $V_R = 0, f = 1 \text{ MHz}$	$C_{\text{tot}}$	-	4	pF
Voltage Rise when Switching ON tested with 50 mA Forward Pulses $t_p = 0.1 \text{ s}$ , Rise Time < 30 ns, $f_p = 5$ to 100 KHz	$V_{\text{fr}}$	-	2.5	V
Reverse Recovery Time at $I_F = 10 \text{ mA}$ to $I_R = 1 \text{ mA}$ , $I_{\text{rr}} = 0.1 \times I_R$ , $V_R = 6 \text{ V}$ , $R_L = 100 \Omega$	$t_{\text{rr}}$	-	4	ns
Thermal Resistance Junction to Ambient Air	$R_{\text{thA}}$	-	0.35 <sup>1)</sup>	K/mW
Rectification Efficiency at $f = 100 \text{ MHz}$ , $V_{\text{RF}} = 2 \text{ V}$	$\eta_V$	0.45	-	-
1) Valid provided that electrodes are kept at ambient temperature.				


**Rectification Efficiency Measurement Circuit**



■ LL-34/SOD-80



**DIMENSIONS (mm are the original dimensions)**

UNIT	A	B	C
mm	3.30	1.30	0.28
	3.70	1.60	0.50

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